## FEATURES

- High-Bandwidth Data Paths - Up to 800 MHz
- Specified Break-Before-Make Switching
- Control Inputs Reference to $\mathrm{V}_{10}$
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 2.3-V to 3.6-V Power Supply ( $\mathrm{V}_{+}$)
- $1.65-\mathrm{V}$ to $1.95-\mathrm{V}$ Logic Supply ( $\mathrm{V}_{10}$ )
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
- 4000-V Human-Body Model (A114-B, Class II)
- 1000-V Charged-Device Model (C101)
- 200-V Machine Model (A115-A)


## APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Low-Voltage Differential Signal Routing

| YZT PACKAGE <br> (BOTTOM THROUGH VIEW) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | A B | C D |  |
|  | 1 | (3) (4) (9) (10) |  |  |
|  | 2 | (2) (5) | (8) (11) |  |
|  | 3 | (1) (6) | (7) (12) |  |
|  | A | B | C | D |
| 1 | IN1 | NO1 | COM1 | NC1 |
| 2 | $\mathrm{V}_{10}$ | GND | GND | $\mathrm{V}_{+}$ |
| 3 | IN2 | NO2 | COM2 | NC2 |

## DESCRIPTION/ORDERING INFORMATION

The TS3DS26227 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 2.3 V to 3.6 V . The device offers high-bandwidth data paths, and a break-before-make feature to prevent signal distortion during the transferring of a signal from one path to another. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable applications.
The TS3DS26227 has a separate logic supply pin $\left(\mathrm{V}_{10}\right)$ that operates from 1.65 V to 1.95 V . $\mathrm{V}_{10}$ powers the control circuitry, which allows the TS3DS26227 to be controlled by $1.8-\mathrm{V}$ signals.

ORDERING INFORMATION

| $\mathbf{T}_{\mathbf{A}}$ | PACKAGE ${ }^{(1)(2)}$ |  | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
| :---: | :--- | :--- | :--- | :--- |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | NanoFree <br>  <br> $0.23-\mathrm{mm}$ Large Bump - YZGA (Pb-free) <br> $0.2625-\mathrm{mm}$ max height | Tape and reel | TS3DS26227YZTR | 267 |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
(2) YZT: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition ( $1=\mathrm{SnPb}, \bullet=\mathrm{Pb}$-free).

[^0]SUMMARY OF CHARACTERISTICS ${ }^{(1)}$

| Configuration | Dual 2:1 <br> Multiplexer/Demultiplexer <br> $(2 \times$ SPDT $)$ |
| :--- | :---: |
| Number of channels | 2 |
| ON-state resistance $\left(\mathrm{r}_{\text {on }}\right)$ | $5 \Omega \mathrm{max}$ |
| ON-state resistance match $\left(\Delta \mathrm{r}_{\text {on }}\right)$ | $0.1 \Omega \mathrm{max}$ |
| ON-state resistance flatness $\left[\mathrm{r}_{\text {onf(lata }}\right]$ |  |

(1) $\mathrm{V}_{+}=2.7 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

## FUNCTION TABLE

| IN | NC TO COM, <br> COM TO NC | NO TO COM, <br> COM TO NO |
| :---: | :---: | :---: |
| L | ON | OFF |
| $H$ | OFF | ON |

## Absolute Maximum Ratings ${ }^{(1)(2)}$

over operating free-air temperature range (unless otherwise noted)

|  |  |  | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \mathrm{V}_{+} \\ & \mathrm{V}_{10} \end{aligned}$ | Supply voltage range ${ }^{(3)}$ |  | -0.5 | 4.6 | V |
| $\mathrm{V}_{\mathrm{NC}}$ <br> $\mathrm{V}_{\mathrm{NO}}$ <br> $\mathrm{V}_{\mathrm{COM}}$ | Analog voltage range ${ }^{(3)(4)(5)}$ |  | -0.5 | $\mathrm{V}_{+}+0.5$ | V |
| $\mathrm{I}_{\mathrm{K}}$ | Analog port diode current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{~V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{COM}}<0 \text {, or } \mathrm{V}_{\mathrm{NC}},$ $\mathrm{V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{COM}}>\mathrm{V}_{+}+0.5$ | -50 | 50 | mA |
| ${ }^{1} \mathrm{NC}$ ${ }^{\prime}$ No $\mathrm{I}_{\text {Com }}$ | On-state switch current | $\mathrm{V}_{\mathrm{NC}}, \mathrm{V}_{\mathrm{NO}}, \mathrm{V}_{\mathrm{COM}}=0$ to $\mathrm{V}_{+}$ | -64 | 64 | mA |
|  | On-state peak switch current ${ }^{(6)}$ |  | -100 | 100 |  |
| $\mathrm{V}_{1}$ | Digital input voltage range |  | -0.5 | $\mathrm{V}_{10}+0.5$ | V |
| $\mathrm{I}_{\mathrm{IK}}$ | Digital input clamp current ${ }^{(3)(4)}$ | $\mathrm{V}_{1}<0$, or $\mathrm{V}_{1}>\mathrm{V}_{10}+0.5$ | -50 | 50 | mA |
| $\begin{aligned} & I_{+} \\ & I_{\text {GND }} \end{aligned}$ | Continuous current through $\mathrm{V}_{+}$or GND |  | -100 | 100 | mA |
| $\theta_{\text {JA }}$ | Package thermal impedance ${ }^{(7)(8)}$ |  |  | TBD | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature range |  | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3) All voltages are with respect to ground, unless otherwise specified.
(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5) This value is limited to 5.5 V maximum.
(6) Requires clamp diodes on analog port to $\mathrm{V}_{+}$
(7) Pulse at 1 -ms duration $<10 \%$ duty cycle
(8) The package thermal impedance is calculated in accordance with JESD 51-7.

## Electrical Characteristics for 3.3-V Supply ${ }^{(1)}$

$\mathrm{V}_{+}=2.7 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~V}_{10}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| Analog signal range | $\mathrm{V}_{\text {COM }}$, <br> $\mathrm{V}_{\mathrm{NO}}$, <br> $\mathrm{V}_{\mathrm{NC}}$ |  |  |  |  | 0 |  | $\mathrm{V}_{+}$ | $\Omega$ |
| ON-state resistance | $\mathrm{r}_{\text {on }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq 1.6 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 3.5 | 5 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 6 |  |
| ON-state resistance match between channels | $\Delta \mathrm{r}_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=1.6 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 0.05 | 0.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.2 |  |
| ON-state resistance flatness | $\mathrm{r}_{\text {on(flat) }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq 1.6 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 2 | 3 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 4 |  |
| NC, NO OFF leakage current | $\mathrm{I}_{\mathrm{NO}(\mathrm{OFF})}$, $\mathrm{I}_{\mathrm{NC}(\text { OFF })}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=0.3 \mathrm{~V}, \end{aligned}$ | Switch OFF, <br> See Figure 14 | $25^{\circ} \mathrm{C}$ | 3.6 V | -5 | 0.1 | 5 | nA |
|  |  |  |  | Full |  | -15 |  | 15 |  |
| NC, NO ON leakage current | $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$, $\mathrm{I}_{\mathrm{NC}(\mathrm{ON})}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\mathrm{Open}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\text { Open, } \\ & \hline \end{aligned}$ | Switch ON, <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 | 0.2 | 10 | nA |
|  |  |  |  | Full |  | -30 |  | 30 |  |
| COM <br> ON leakage current | $\mathrm{I}_{\text {COM(ON }}$ | $\mathrm{V}_{\mathrm{NO}}$ or $\mathrm{V}_{\mathrm{NC}}=$ Open, <br> $\mathrm{V}_{\text {COM }}=0.3 \mathrm{~V}$, <br> or <br> $\mathrm{V}_{\mathrm{NO}}$ or $\mathrm{V}_{\mathrm{NC}}=$ Open, <br> $\mathrm{V}_{\text {COM }}=3 \mathrm{~V}$, | Switch ON, <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 | 0.2 | 10 | nA |
|  |  |  |  | Full |  | -30 |  | 30 |  |
| Digital Control Inputs (IN1, IN2) ${ }^{(2)}$ |  |  |  |  |  |  |  |  |  |
| Input logic high | $\mathrm{V}_{\mathrm{IH}}$ | $\mathrm{V}_{10}=1.65 \mathrm{~V}$ to 1.95 V |  | Full |  | $\begin{array}{r} 0.65 \\ \times V_{10} \\ \hline \end{array}$ |  | $\mathrm{V}_{10}$ | V |
| Input logic low | VIL | $\mathrm{V}_{\mathrm{IO}}=1.65 \mathrm{~V}$ to 1.95 V |  | Full |  | 0 |  | $\begin{array}{r} 0.35 \\ \times V_{10} \\ \hline \end{array}$ | V |
| Input leakage current | $\mathrm{I}_{\mathrm{IH}}, \mathrm{I}_{\text {IL }}$ | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{10}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 3.6 V | -2 |  | 2 | nA |
|  |  |  |  | Full |  | -10 |  | 10 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $\mathrm{V}_{10}$ or GND to ensure proper device operation. Refer to the Tl application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## Electrical Characteristics for 3.3-V Supply (continued)

$\mathrm{V}_{+}=2.7 \mathrm{~V}$ to $3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{IO}}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS |  | $\mathrm{T}_{\mathrm{A}}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| Turn-on time | $\mathrm{t}_{\mathrm{on}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 17 | $25^{\circ} \mathrm{C}$ | 3.3 V | 1 | 6.5 | 9 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.7 \text { to } \\ & 3.6 \mathrm{~V} \end{aligned}$ | 1 |  | 11.5 |  |
| Turn-off time | toff | $\begin{aligned} & \mathrm{V}_{\text {COM }}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\begin{aligned} & \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF}, \\ & \text { See Figure } 17 \end{aligned}$ | $25^{\circ} \mathrm{C}$ | 3.3 V | 1 | 2 | 4 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.7 \mathrm{to} \\ & 3.6 \mathrm{~V} \end{aligned}$ | 1 |  | 5 |  |
| Break-before-make time | $\mathrm{t}_{\text {BBM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=0.6 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 18 | $25^{\circ} \mathrm{C}$ | 3.3 V | 0.5 | 4 | 8 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.7 \mathrm{to} \\ & 3.6 \mathrm{~V} \end{aligned}$ | 0.5 |  | 9 |  |
| Charge injection | $\mathrm{Q}_{\mathrm{C}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $C_{L}=1 \mathrm{nF},$ <br> See Figure 22 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 5.5 |  | pC |
| NC, NO OFF capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}$, <br> $\mathrm{C}_{\mathrm{NO} \text { (OFF) }}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.3 \mathrm{~V}$ or GND, Switch OFF, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 3.5 |  | pF |
| NC, NO ON capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{ON})}$, <br> $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.3 \mathrm{~V}$ or GND, Switch ON, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 10.5 |  | pF |
| COM <br> ON capacitance | $\mathrm{C}_{\text {Com(ON) }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=1.3 \mathrm{~V} \text { or GND, } \\ & \text { Switch ON, } \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 10.5 |  | pF |
| Digital input capacitance | $\mathrm{C}_{1}$ | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 3.3 V |  | 2 |  | pF |
| Bandwidth | BW | $\begin{array}{\|l} \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ \text { Switch ON, } \end{array}$ | See Figure 19 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | 800 |  | MHz |
| OFF isolation | $\mathrm{O}_{\text {ISO }}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=200 \mathrm{MHz}, \end{aligned}$ | Switch OFF, <br> See Figure 20 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | -40 |  | dB |
| Crosstalk | $\mathrm{X}_{\text {TALK }}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=200 \mathrm{MHz}, \end{aligned}$ | Switch ON, <br> See Figure 21 | $25^{\circ} \mathrm{C}$ | 2.7 V |  | -39 |  | dB |
| Supply |  |  |  |  |  |  |  |  |  |
| Positive supply current | $I_{+}$ | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 3.6 V | -20 | 1 | 20 | nA |
|  |  |  |  | Full |  | -500 |  | 500 |  |
| Logic supply current | $1{ }_{10}$ | $\mathrm{V}_{1}=\mathrm{V}_{10}$ or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 3.6 V | -10 | 1 | 10 | nA |
|  |  |  |  | Full |  | -200 |  | 200 |  |

## Electrical Characteristics for 2.5-V Supply ${ }^{(1)}$

$\mathrm{V}_{+}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~V}_{10}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS |  | TA | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| Analog signal range | $V_{\text {COM, }}$ <br> $\mathrm{V}_{\mathrm{NO}}$, <br> $\mathrm{V}_{\mathrm{NC}}$ |  |  |  |  | 0 |  | $\mathrm{V}_{+}$ | $\Omega$ |
| ON-state resistance | $r_{\text {on }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq 1.3 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 4 | 5.5 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 7 |  |
| ON-state resistance match between channels | $\Delta r_{\text {on }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=1.3 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 0.05 | 0.1 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 0.2 |  |
| ON-state resistance flatness | $\mathrm{r}_{\text {on(lat) }}$ | $\begin{aligned} & 0 \leq\left(\mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}\right) \leq 1.3 \mathrm{~V}, \\ & \mathrm{I}_{\mathrm{COM}}=-10 \mathrm{~mA}, \end{aligned}$ | Switch ON, <br> See Figure 13 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 2.5 | 4 | $\Omega$ |
|  |  |  |  | Full |  |  |  | 4.5 |  |
| NC, NO OFF leakage current | $\mathrm{I}_{\mathrm{NO}(\text { OFF })}$, $\mathrm{I}_{\mathrm{NC}(\mathrm{OFF})}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.2 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=2.3 \mathrm{~V}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=0.2 \mathrm{~V}, \\ & \hline \end{aligned}$ | Switch OFF, <br> See Figure 14 | $25^{\circ} \mathrm{C}$ | 2.7 V | -5 | 0.1 | 5 | nA |
|  |  |  |  | Full |  | -15 |  | 15 |  |
| NC, NO ON leakage current | $\mathrm{I}_{\mathrm{NO}(\mathrm{ON})}$, $\mathrm{I}_{\mathrm{NC}(\mathrm{ON})}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=0.2 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\mathrm{Open}, \\ & \text { or } \\ & \mathrm{V}_{\mathrm{NO}} \text { or } \mathrm{V}_{\mathrm{NC}}=2.3 \mathrm{~V}, \\ & \mathrm{~V}_{\mathrm{COM}}=\mathrm{Open}, \end{aligned}$ | Switch ON, <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 2.7 V | -5 | 0.2 | 5 | nA |
|  |  |  |  | Full |  | -20 |  | 20 |  |
| COM <br> ON leakage current | $\mathrm{I}_{\text {COM(ON) }}$ | $\mathrm{V}_{\mathrm{NO}}$ or $\mathrm{V}_{\mathrm{NC}}=$ Open, <br> $\mathrm{V}_{\text {COM }}=0.2 \mathrm{~V}$, <br> or <br> $\mathrm{V}_{\mathrm{NO}}$ or $\mathrm{V}_{\mathrm{NC}}=$ Open, <br> $\mathrm{V}_{\mathrm{COM}}=2.3 \mathrm{~V}$, | Switch ON, <br> See Figure 15 | $25^{\circ} \mathrm{C}$ | 2.7 V | -1 | 0.05 | 1 | nA |
|  |  |  |  | Full |  | -10 |  | 10 |  |
| Digital Control Inputs (IN1, IN2) ${ }^{(2)}$ |  |  |  |  |  |  |  |  |  |
| Input logic high | $\mathrm{V}_{\mathrm{IH}}$ | $\mathrm{V}_{\mathrm{IO}}=1.65 \mathrm{~V}$ to 1.95 V |  | Full |  | $\begin{array}{r} 0.65 \\ \times V_{10} \end{array}$ |  | $\mathrm{V}_{10}$ | V |
| Input logic low | VIL | $\mathrm{V}_{\mathrm{IO}}=1.65 \mathrm{~V}$ to 1.95 V |  | Full |  | 0 |  | $\begin{array}{r} 0.35 \\ \times V_{10} \\ \hline \end{array}$ | V |
| Input leakage current | $\mathrm{I}_{\text {IH }}, \mathrm{I}_{\text {IL }}$ | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{10}$ or 0 |  | $25^{\circ} \mathrm{C}$ | 2.7 V | -1 | 0.05 | 1 | nA |
|  |  |  |  | Full |  | -10 |  | 10 |  |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(2) All unused digital inputs of the device must be held at $\mathrm{V}_{10}$ or GND to ensure proper device operation. Refer to the Tl application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## Electrical Characteristics for 2.5-V Supply (continued)

$\mathrm{V}_{+}=2.3 \mathrm{~V}$ to $2.7 \mathrm{~V}, \mathrm{~V}_{10}=1.65 \mathrm{~V}$ to $1.95 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ (unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITIONS |  | $\mathrm{T}_{\mathrm{A}}$ | $\mathrm{V}_{+}$ | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Dynamic |  |  |  |  |  |  |  |  |  |
| Turn-on time | $\mathrm{t}_{\mathrm{on}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 17 | $25^{\circ} \mathrm{C}$ | 2.5 V | 1 | 7 | 11 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ | 1 |  | 13 |  |
| Turn-off time | toff | $\begin{aligned} & \mathrm{V}_{\text {COM }}=\mathrm{V}_{+}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 17 | $25^{\circ} \mathrm{C}$ | 2.5 V | 1 | 2.5 | 4.5 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \mathrm{to} \\ & 2.7 \mathrm{~V} \end{aligned}$ | 1 |  | 5.5 |  |
| Break-before-make time | $\mathrm{t}_{\text {BBM }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{NC}}=\mathrm{V}_{\mathrm{NO}}=0.6 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=50 \Omega, \end{aligned}$ | $\mathrm{C}_{\mathrm{L}}=35 \mathrm{pF},$ <br> See Figure 18 | $25^{\circ} \mathrm{C}$ | 2.3 V | 1 | 4 | 8 | ns |
|  |  |  |  | Full | $\begin{aligned} & 2.3 \text { to } \\ & 2.7 \mathrm{~V} \end{aligned}$ | 1 |  | 10 |  |
| Charge injection | $\mathrm{Q}_{\mathrm{C}}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{GEN}}=0, \\ & \mathrm{R}_{\mathrm{GEN}}=0, \end{aligned}$ | $C_{L}=1 \mathrm{nF}$ <br> See Figure 22 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 4 |  | pC |
| NC, NO OFF capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}$, <br> $\mathrm{C}_{\mathrm{NO} \text { (OFF) }}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.6 \mathrm{~V}$ or GND, Switch OFF, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 3.5 |  | pF |
| NC, NO ON capacitance | $\mathrm{C}_{\mathrm{NC}(\mathrm{ON})}$, <br> $\mathrm{C}_{\mathrm{NO}(\mathrm{ON})}$ | $\mathrm{V}_{\mathrm{NC}}$ or $\mathrm{V}_{\mathrm{NO}}=1.6 \mathrm{~V}$ or GND, Switch ON, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 10.5 |  | pF |
| COM ON capacitance | $\mathrm{C}_{\text {Com(ON) }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{COM}}=1.6 \mathrm{~V} \text { or GND, } \\ & \text { Switch ON, } \end{aligned}$ | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 10.5 |  | pF |
| Digital input capacitance | $\mathrm{C}_{1}$ | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | See Figure 16 | $25^{\circ} \mathrm{C}$ | 2.5 V |  | 2 |  | pF |
| Bandwidth | BW | $\begin{array}{\|l} \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ \text { Switch ON, } \end{array}$ | See Figure 19 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | 800 |  | MHz |
| OFF isolation | $\mathrm{O}_{\text {ISO }}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=200 \mathrm{MHz}, \end{aligned}$ | Switch OFF, <br> See Figure 20 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | -40 |  | dB |
| Crosstalk | $\mathrm{X}_{\text {TALK }}$ | $\begin{aligned} & \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ & \mathrm{f}=200 \mathrm{MHz}, \end{aligned}$ | Switch ON, <br> See Figure 21 | $25^{\circ} \mathrm{C}$ | 2.3 V |  | -39 |  | dB |
| Supply |  |  |  |  |  |  |  |  |  |
| Positive supply current | $I_{+}$ | $\mathrm{V}_{1}=\mathrm{V}_{+}$or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 2.7 V | -10 | 1 | 10 | nA |
|  |  |  |  | Full |  | -350 |  | 350 |  |
| Logic supply current | $1{ }_{10}$ | $\mathrm{V}_{1}=\mathrm{V}_{10}$ or GND, | Switch ON or OFF | $25^{\circ} \mathrm{C}$ | 2.7 V | -5 | 1 | 5 | nA |
|  |  |  |  | Full |  | -200 |  | 200 |  |

TYPICAL CHARACTERISTICS


Figure 1. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\mathrm{I}}(\mathrm{NC}, \mathrm{NO}$, or COM$)\left(\mathrm{V}_{+}=2.3 \mathrm{~V}\right)$


Figure 3. Analog Switch Leakage Current vs $\mathrm{V}_{\mathrm{I}}$ (NC, NO, or COM) $\left(\mathrm{V}_{+}=3.6 \mathrm{~V}\right)$


Figure 5. Charge Injection vs $\mathbf{V}_{\text {com }}$


Figure 2. $\mathrm{r}_{\text {on }}$ vs $\mathrm{V}_{\mathrm{I}}(\mathrm{NC}, \mathrm{NO}$, or COM$)\left(\mathrm{V}_{+}=2.7 \mathrm{~V}\right)$


Figure 4. $\mathrm{I}_{+}$Supply Current vs $\mathrm{V}_{+}$


Figure 6. $\mathrm{t}_{\mathrm{on}} / \mathrm{t}_{\text {off }} \mathrm{Vs} \mathrm{V}_{\boldsymbol{+}}$

HIGH-BANDWIDTH DUAL-SPDT DIFFERENTIAL SIGNAL SWITCH WITH INPUT LOGIC TRANSLATION

TYPICAL CHARACTERISTICS (continued)


Figure 7. $\mathrm{t}_{\mathrm{on}} / \mathrm{t}_{\text {off }} \mathrm{vs}$ Temperature $\left(\mathrm{V}_{+}=2.3 \mathrm{~V}\right)$


Figure 9. OFF Isolation vs Frequency $\left(\mathrm{V}_{+}=2.5 \mathrm{~V}\right)$


Figure 11. Threshold Voltage ( $\mathrm{V}_{10}=1.8 \mathrm{~V}, \mathrm{~V}_{+}=2.7 \mathrm{~V}$ )


Figure 8. Bandwidth $\left(\mathrm{V}_{+}=2.5 \mathrm{~V}\right)$


Figure 10. Crosstalk vs Frequency ( $\mathrm{V}_{+}=2.5 \mathrm{~V}$ )


Figure 12. Threshold Voltage ( $\left.\mathrm{V}_{10}=1.8 \mathrm{~V}, \mathrm{~V}_{+}=3.6 \mathrm{~V}\right)$

PARAMETER MEASUREMENT INFORMATION


Figure 13. ON-State Resistance ( $\mathrm{r}_{\mathrm{on}}$ )


Figure 14. OFF-State Leakage Current (ICOM(OFF), $\left.I_{\text {NC(OFF) }}, I_{\text {COM(PWROFF) }}, I_{\text {NC(PWROFF) }}\right)$


Figure 15. ON-State Leakage Current ( $\left.\mathrm{I}_{\mathrm{COM}(\mathrm{ON})}, \mathrm{I}_{\mathrm{NC}(\mathrm{ON})}\right)$

PARAMETER MEASUREMENT INFORMATION (continued)

$\mathrm{V}_{\text {BIAS }}=1.3 \mathrm{~V}, 1.6 \mathrm{~V}$, or GND and $\mathrm{V}_{\mathrm{I}}=\mathrm{V}_{\mathrm{IO}}$ or GND
Capacitance is measured at NO, COM, and IN inputs during ON and OFF conditions.

Figure 16. Capacitance ( $\left.\mathrm{C}_{\mathrm{I}}, \mathrm{C}_{\text {COM(OFF) })}, \mathrm{C}_{\mathrm{COM}(\mathrm{ON})}, \mathrm{C}_{\mathrm{NC}(\mathrm{OFF})}, \mathrm{C}_{\mathrm{NC}(\mathrm{ON})}\right)$

${ }^{(1)}$ All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
(2) $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 17. Turn-On ( $\mathrm{t}_{\mathrm{ON}}$ ) and Turn-Off Time ( $\mathrm{t}_{\mathrm{OFF}}$ )

PARAMETER MEASUREMENT INFORMATION (continued)

(1) All input pulses are supplied by generators having the following characteristics: $\mathrm{PRR} \leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.
(2) $C_{L}$ includes probe and jig capacitance.

Figure 18. Break-Before-Make Time ( $\mathrm{t}_{\mathrm{BBM}}$ )


Figure 19. Bandwidth (BW)

HIGH-BANDWIDTH DUAL-SPDT DIFFERENTIAL SIGNAL SWITCH
WITH INPUT LOGIC TRANSLATION

PARAMETER MEASUREMENT INFORMATION (continued)


Figure 20. OFF Isolation ( $\mathrm{O}_{\text {ISo }}$ )


Figure 21. Crosstalk ( $\mathrm{X}_{\text {tALK }}$ )

PARAMETER MEASUREMENT INFORMATION (continued)

(1) $C_{L}$ includes probe and jig capacitance.
(2) All input pulses are supplied by generators having the following characteristics: PRR $\leq 10 \mathrm{MHz}, \mathrm{Z}_{\mathrm{O}}=50 \Omega, \mathrm{t}_{\mathrm{r}}<5 \mathrm{~ns}, \mathrm{t}_{\mathrm{f}}<5 \mathrm{~ns}$.

Figure 22. Charge Injection $\left(Q_{C}\right)$

(1) $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 23. Total Harmonic Distortion (THD)

## PACKAGING INFORMATION

| Orderable Device | Status <br> (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan <br> (2) | Lead finish/ Ball material (6) | MSL Peak Temp <br> (3) | Op Temp ( ${ }^{\circ} \mathrm{C}$ ) | Device Marking <br> (4/5) | Samples |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3DS26227YZTR | ACTIVE | DSBGA | YZT | 12 | 3000 | RoHS \& Green | SNAGCU | Level-1-260C-UNLIM | -40 to 85 | (262, 26N) | Samples |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: Tl defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement
${ }^{(3)}$ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
${ }^{(4)}$ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
${ }^{(5)}$ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
${ }^{(6)}$ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width

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TAPE AND REEL INFORMATION


TAPE DIMENSIONS


| A0 | Dimension designed to accommodate the component width |
| :--- | :--- |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

Reel Width (W1)
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> W1 $(\mathbf{m m})$ | A0 <br> $(\mathbf{m m})$ | B0 <br> $(\mathbf{m m})$ | K0 <br> $(\mathbf{m m})$ | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3DS26227YZTR | DSBGA | YZT | 12 | 3000 | 178.0 | 9.2 | 1.49 | 1.99 | 0.75 | 4.0 | 8.0 | Q2 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| TS3DS26227YZTR | DSBGA | YZT | 12 | 3000 | 220.0 | 220.0 | 35.0 |

YZT (R-XBGA-N12)


NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. NanoFree ${ }^{T M}$ package configuration.

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